

Product data sheet

1. General description

Planar passivated guaranteed commutation triac in a SOT223 surface mountable plastic package for use in motor control circuits or with other highly inductive loads. This triac balances the requirements of commutation performance and gate sensitivity and is intended for interfacing with low power drivers, including micro controllers.

2. Features and benefits

- 3Q technology for improved noise immunity •
- Direct triggering from low power drivers and logic ICs •
- High commutation capability with sensitive gate
- High immunity to false turn-on by dV/dt with sensitive gate •
- Planar passivated for voltage ruggedness and reliability •
- Sensitive gate for easy logic level triggering
- Surface mountable package

3. Applications

- General purpose motor controls
- Small loads in washing machines
- Rectifier-fed DC inductive loads e.g. DC motors and solenoids

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	600	V
I _{T(RMS)}	RMS on-state current	rent full sine wave; $T_{sp} \le 108 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3		-	1	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t _p = 16.7 ms	-	-	11	A
		full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	10	A
Tj	junction temperature		-	-	125	°C
Static chara	acteristics		·			
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 9</u>	-	-	10	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _i = 25 °C; <u>Fig. 9</u>	-	-	10	mA

BTA204W-600E

3Q Hi-Com Triac

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 11</u>	-	-	12	mA
V _T	on-state voltage	I _T = 2 A; T _j = 25 °C; <u>Fig. 12</u>	-	1.2	1.5	V
Dynamic ch	naracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 600 V; T_j = 125 °C; (67% of V_{DRM}); exponential waveform; gate open circuit	30	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 1 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu \text{s}; \text{ (snubberless condition); gate open circuit}$	2	-	-	A/ms

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol		
1	T1	main terminal 1	4			
2	T2	main terminal 2	□ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □	Sym051		
3	G	gate		Symust		
4	mb	mounting base; connected to main terminal 2				

6. Ordering information

Table 3. Ordering information						
Type number	Package	ackage				
	Name	Description	Version			
BTA204W-600E	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			

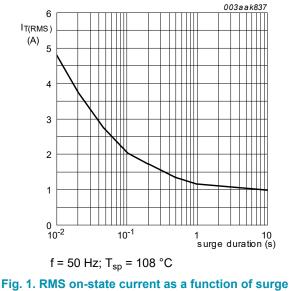


7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{sp} \le 108 \text{ °C}$; <u>Fig. 1; Fig. 2</u> ; Fig. 3	-	1	A
	non-repetitive peak on-	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	11	А
	state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5	-	10	A
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.5	A²s
dl _T /dt	rate of rise of on-state current	I _G = 0.2 A	-	100	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



duration; maximum values

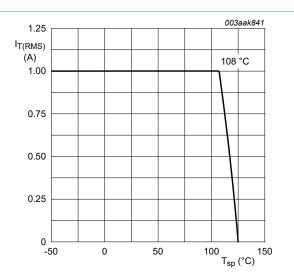
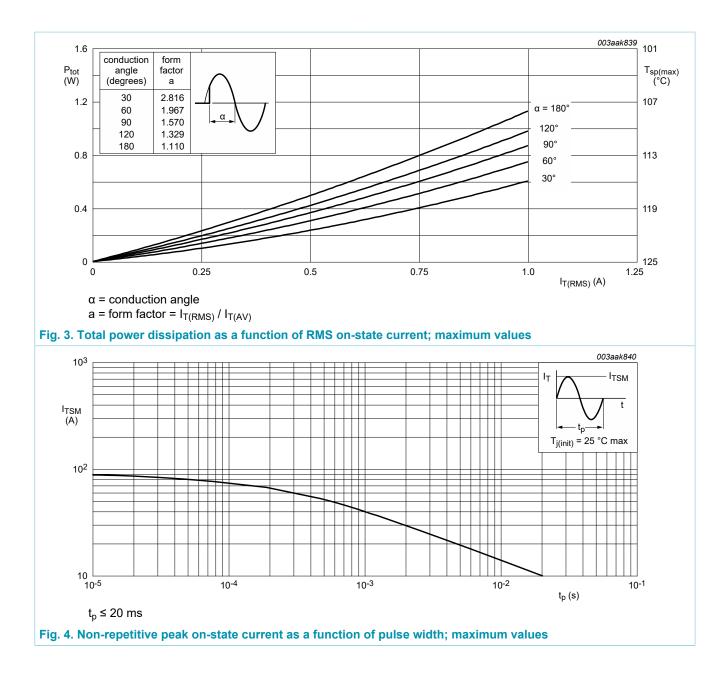


Fig. 2. RMS on-state current as a function of solder point temperature; maximum values

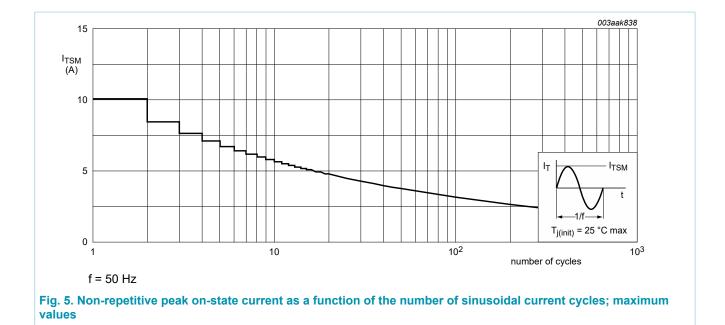
BTA204W-600E

3Q Hi-Com Triac



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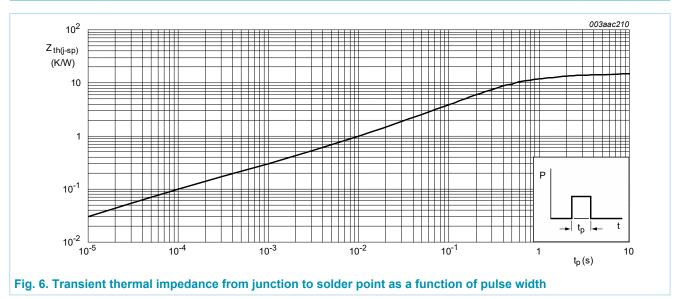
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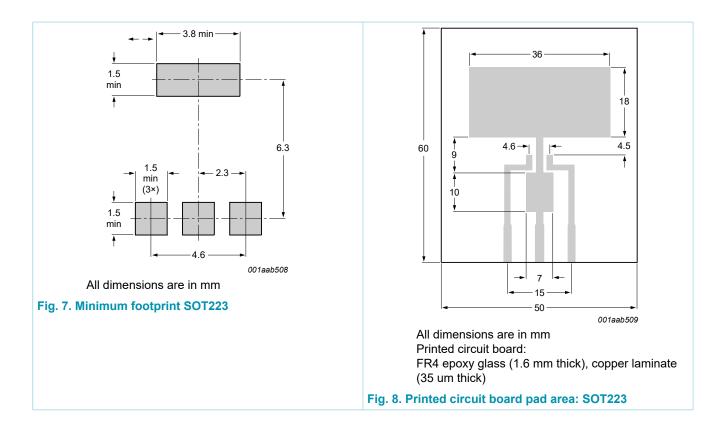
8. Thermal characteristics

Table 5. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point	full cycle or half cycle; <u>Fig. 6</u>		-	-	15	K/W
R _{th(j-a)}	thermal resistance from junction to	in free air; printed circuit board mounted; minimum footprint; Fig. 7		-	156	-	K/W
	ambient free air	in free air; printed circuit board mounted; pad area; Fig. 8		-	70	-	K/W



BTA204W-600E

3Q Hi-Com Triac



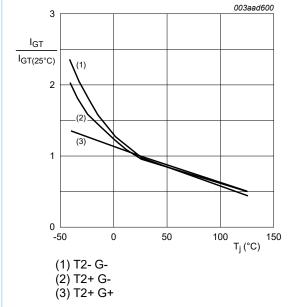


9. Characteristics

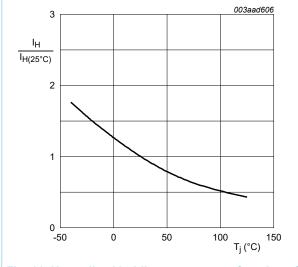
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 9</u>	-	-	10	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	10	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	10	mA
ΙL	latching current	V_D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; Fig. 10	-	-	12	mA
		V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 10</u>	-	-	18	mA
		V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 10</u>	-	-	12	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 11</u>	-	-	12	mA
V _T	on-state voltage	I _T = 2 A; T _j = 25 °C; <u>Fig. 12</u>	-	1.2	1.5	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 13</u>	-	0.7	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; <u>Fig. 13</u>	0.25	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic ch	naracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 600 V; T _j = 125 °C; (67% of V_{DRM}); exponential waveform; gate open circuit	30	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	V_D = 400 V; T_j = 125 °C; $I_{T(RMS)}$ = 1 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit	2	-	-	A/ms

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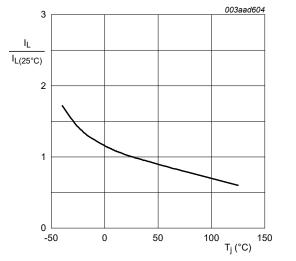
3Q Hi-Com Triac



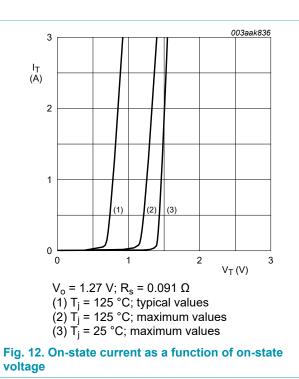






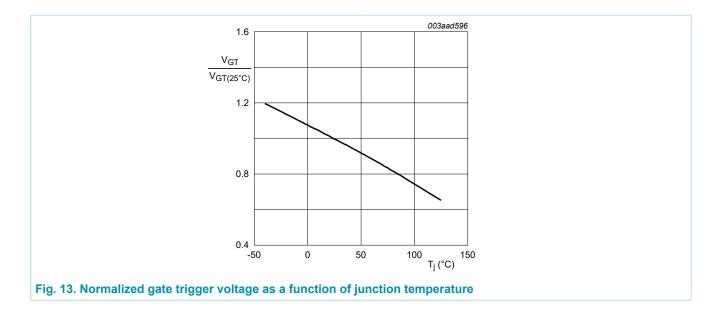






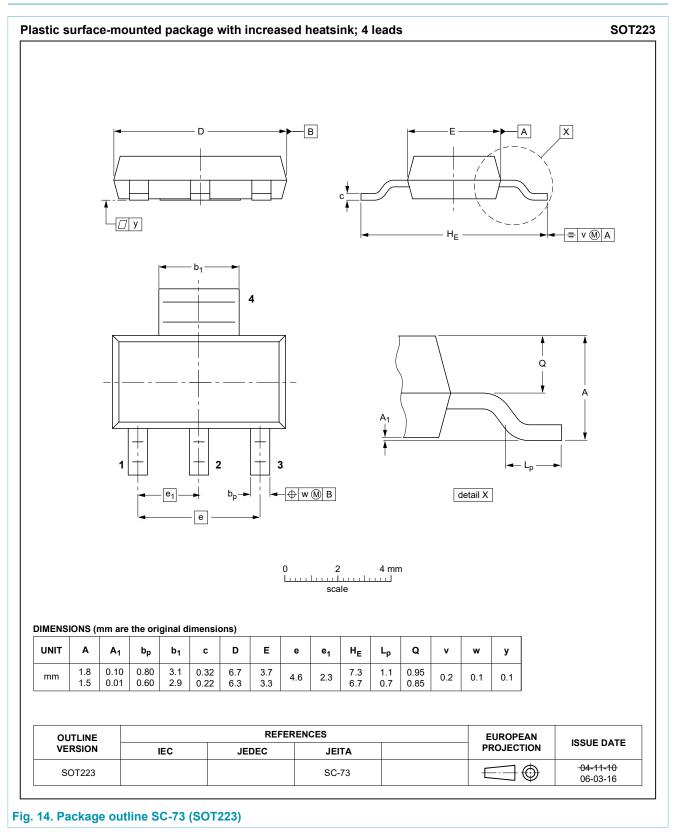
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10. Package outline



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11. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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